



BOURNS®

TISP4070J3BJ THRU TISP4395J3BJ

BIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTORS

TISP4xxxJ3BJ Overvoltage Protector Series

Ion-Implanted Breakdown Region
- Precise and Stable Voltage

Low Voltage Overshoot Under Surge

Designed for Transformer Center Tap (Ground Return) Overvoltage Protection
- Enables GR-1089-CORE Compliance
- High Holding Current Allows Protection of Data Lines with d.c Power Feed

Can be Used to Protect Rugged Modems Designed for Exposed Applications Exceeding TIA-968-A

Device Name	V _{DRM} V	V _(BO) V
TISP4070J3BJ	58	70
TISP4080J3BJ	65	80
TISP4095J3BJ	75	95
TISP4115J3BJ	90	115
TISP4125J3BJ	100	125
TISP4145J3BJ	120	145
TISP4165J3BJ	135	165
TISP4180J3BJ	145	180
TISP4200J3BJ	155	200
TISP4219J3BJ	180	219
TISP4250J3BJ	190	250
TISP4290J3BJ	220	290
TISP4350J3BJ	275	350
TISP4395H3BJ	320	395



.....UL Recognized Component

SMB Package (Top View)



MD-SMB-004-a

Device Symbol



SD-TISP4xxx-001-a

Rated for International Surge Wave Shapes

Wave Shape	Standard	I _{PPSM} A
2/10	GR-1089-CORE	1000
8/20	IEC 61000-4-5	800
10/160	TIA-968-A	400
10/700	ITU-T K.20/21/45	350
10/560	TIA-968-A	250
10/1000	GR-1089-CORE	200

Description

The range of TISP4xxxJ3BJ devices is designed to limit overvoltages on telecom lines. The TISP4xxxJ3BJ is primarily designed to address GR-1089-CORE compliance on data transmission lines with d.c. power feeding. When overvoltage protection is applied to transformer coupled lines from the transformer center tap to ground, the total ground return current can be 200 A, 10/1000 and 1000 A, 2/10. The high 150 mA holding current is set above common d.c. feed system levels to allow the TISP4xxxJ3BJ to reset following a disturbance.

These devices allow signal voltages, without clipping, up to the maximum off-state voltage value, V_{DRM}, see Figure 1. Voltages above V_{DRM} are limited and will not exceed the breakdown voltage, V_(BO), level. If sufficient current flows due to the overvoltage, the device switches into a low voltage on-state condition, which diverts the current from the overvoltage through the device. When the diverted current falls below the holding current, I_H, level the devices switches off and restores normal system operation.

How to Order

Device	Package	Carrier	Order As	Marking Code	Standard Quantity
TISP4xxxJ3BJ	SMB	Embossed Tape Reeled	TISP4xxxJ3BJR-S	4xxxJ3	3000

Insert xxx corresponding to device name.

*RoHS Directive 2002/95/EC Jan 27 2003 including Annex JULY 2003 – REVISED MAY 2007

Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications.

TISP4xxxJ3BJ Overvoltage Protector Series

BOURNS®

Absolute Maximum Ratings, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	'4070J3BJ	± 58
		'4080J3BJ	± 65
		'4095J3BJ	± 75
		'4115J3BJ	± 90
		'4125J3BJ	± 100
		'4145J3BJ	± 120
		'4165J3BJ	± 135
		'4180J3BJ	± 145
		'4200J3BJ	± 155
		'4219J3BJ	± 180
		'4250J3BJ	± 190
		'4290J3BJ	± 220
		'4350J3BJ	± 275
		'4395J3BJ	± 320
Non-repetitive peak impulse current (see Notes 1 and 2)	I_{PPSM}	± 1000	
2/10 μs (GR-1089-CORE, 2/10 μs voltage wave shape)		± 800	
8/20 μs (IEC 61000-4-5, combination wave generator, 1.2/50 μs voltage wave shape)		± 400	
10/160 μs (TIA-968-A, 10/160 μs voltage wave shape)		± 370	
4/250 μs (ITU-T K.20/21, 10/700 μs voltage waveshape, simultaneous)		± 350	
5/310 μs (ITU-T K.20/21, 10/700 μs voltage wave shape, single)		± 350	
5/320 μs (TIA-968-A, 9/720 μs voltage waveshape, single)		± 250	
10/560 μs (TIA-968-A, 10/560 μs voltage wave shape)		± 200	
10/1000 μs (GR-1089-CORE, 10/1000 μs voltage wave shape)	I_{TSM}	50	A
Non-repetitive peak on-state current (see Notes 1 and 2)			
20 ms, 50 Hz (full sine wave)			
Initial rate of rise of on-state current. Linear current ramp. Maximum ramp value < 50 A	dI_T/dt	800	$\text{A}/\mu\text{s}$
Junction temperature	T_J	-40 to +150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-65 to +150	$^\circ\text{C}$

- NOTES: 1. Initially the device must be in thermal equilibrium with $T_J = 25^\circ\text{C}$.
 2. These non-repetitive rated currents are peak values of either polarity. The surge may be repeated after the device returns to its initial conditions.

Electrical Characteristics, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Parameter	Test Conditions	Min	Typ	Max	Unit
I_{DRM}	Repetitive peak off-state current $V_D = V_{\text{DRM}}$	$T_A = 25^\circ\text{C}$ $T_A = 85^\circ\text{C}$	± 5 ± 10	± 10	μA
$V_{(\text{BO})}$	AC Breakover voltage $dv/dt = \pm 250 \text{ V/ms}$, $R_{\text{SOURCE}} = 300 \Omega$	'4070J3BJ	± 70		
		'4080J3BJ	± 80		
		'4095J3BJ	± 95		
		'4115J3BJ	± 115		
		'4125J3BJ	± 125		
		'4145J3BJ	± 145		
		'4165J3BJ	± 165		
		'4180J3BJ	± 180		
		'4200J3BJ	± 200		
		'4219J3BJ	± 219		
		'4250J3BJ	± 250		
		'4290J3BJ	± 290		
		'4350J3BJ	± 350		
		'4395J3BJ	± 395		

TISP4xxxJ3BJ Overvoltage Protector Series

BOURNS®

Electrical Characteristics, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted) (Continued)

Parameter	Test Conditions	Min	Typ	Max	Unit	
$V_{(BO)}$	Ramp breakover voltage dv/dt $\leq \pm 1000 \text{ V}/\mu\text{s}$, Linear voltage ramp, Maximum ramp value = $\pm 500 \text{ V}$ di/dt = $\pm 20 \text{ A}/\mu\text{s}$, Linear current ramp, Maximum ramp value = $\pm 10 \text{ A}$	'4070J3BJ '4080J3BJ '4095J3BJ '4115J3BJ '4125J3BJ '4145J3BJ '4165J3BJ '4180J3BJ '4200J3BJ '4219J3BJ '4250J3BJ '4290J3BJ '4350J3BJ '4395J3BJ			± 77 ± 88 ± 104 ± 125 ± 135 ± 156 ± 177 ± 192 ± 212 ± 231 ± 263 ± 303 ± 364 ± 409	V
$I_{(BO)}$	Breakover current dv/dt = $\pm 250 \text{ V}/\text{ms}$, $R_{\text{SOURCE}} = 300 \Omega$	'4070J3BJ thru '4115J3BJ '4125J3BJ thru '4219J3BJ '4250J3BJ thru '4395J3BJ			± 900 ± 800 ± 600	mA
I_H	Holding current $I_T = \pm 5 \text{ A}$, di/dt = $\pm 30 \text{ mA}/\text{ms}$		± 150		± 600	mA
dv/dt	Critical rate of rise of off-state voltage Linear voltage ramp Maximum ramp value < $0.85V_{\text{DRM}}$		± 5			kV/ μs
I_D	Off-state current $V_D = \pm 50 \text{ V}$		$T_A = 85^\circ\text{C}$		± 10	μA
C_O	f = 1 MHz, $V_d = 1 \text{ V rms}$, $V_D = 0$	'4070J3BJ thru '4115J3BJ '4125J3BJ thru '4219J3BJ '4250J3BJ thru '4395J3BJ	195 120 105	235 145 125		pF
	f = 1 MHz, $V_d = 1 \text{ V rms}$, $V_D = -1 \text{ V}$	'4070J3BJ thru '4115J3BJ '4125J3BJ thru '4219J3BJ '4250J3BJ thru '4395J3BJ	180 110 95	215 132 115		
	f = 1 MHz, $V_d = 1 \text{ V rms}$, $V_D = -2 \text{ V}$	'4070J3BJ thru '4115J3BJ '4125J3BJ thru '4219J3BJ '4250J3BJ thru '4395J3BJ	165 100 90	200 120 105		
	f = 1 MHz, $V_d = 1 \text{ V rms}$, $V_D = -50 \text{ V}$	'4070J3BJ thru '4115J3BJ '4125J3BJ thru '4219J3BJ '4250J3BJ thru '4395J3BJ	85 50 42	100 60 50		
	f = 1 MHz, $V_d = 1 \text{ V rms}$, $V_D = -100 \text{ V}$ (see Note 3)	'4125J3BJ thru '4219J3BJ '4250J3BJ thru '4395J3BJ	40 35	50 40		

NOTE: 3. To avoid possible clipping, the TISP4125J3BJ is tested with $V_D = -98 \text{ V}$.

Thermal Characteristics

Parameter	Test Conditions	Min	Typ	Max	Unit
$R_{\theta JA}$	Junction to ambient thermal resistance EIA/JESD51-3 PCB, $I_T = I_{\text{TSM}(1000)}$ (see Note 4)			90	°C/W

NOTE: 4. EIA/JESD51-2 environment and PCB has standard footprint dimensions connected with 5 A rated printed wiring track widths.

TISP4xxxJ3BJ Overvoltage Protector Series

BOURNS®

Parameter Measurement Information

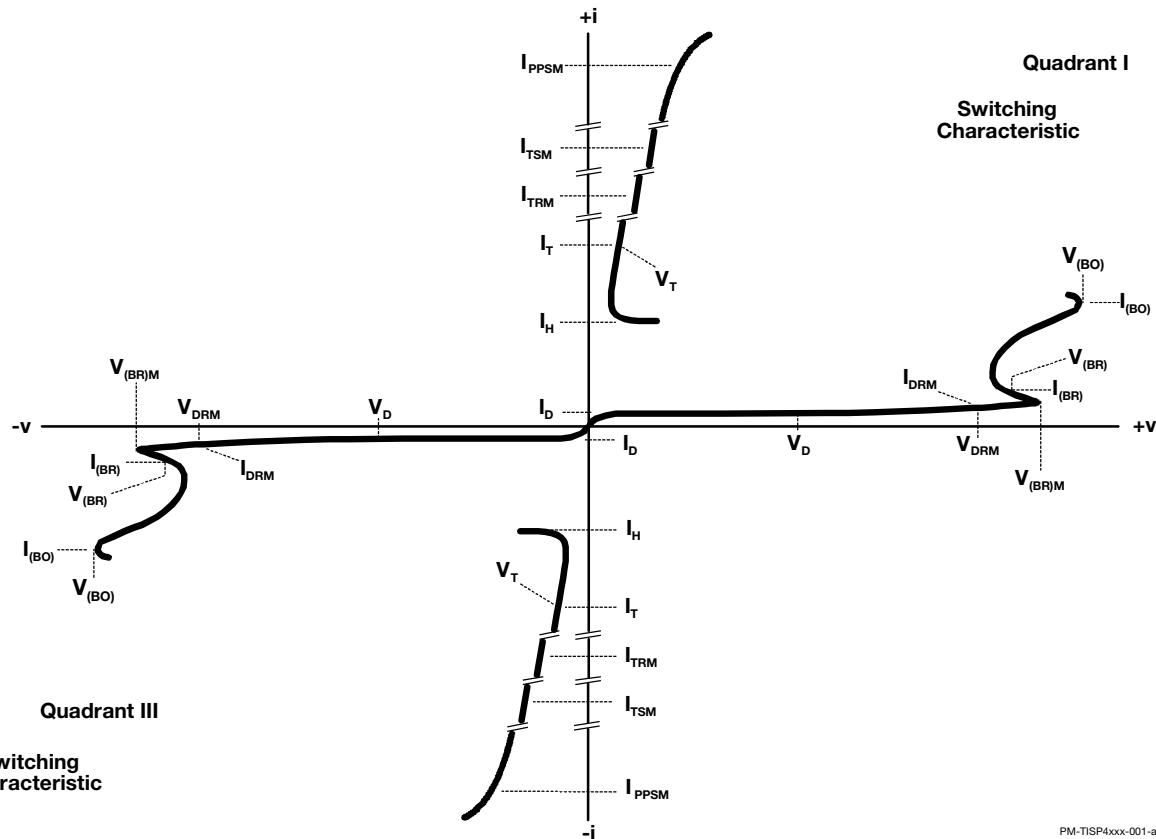


Figure 1. Voltage-Current Characteristic for T and R Terminals
All Measurements are Referenced to the R Terminal

TISP4xxxJ3BJ Overvoltage Protector Series

BOURNS®

Typical Characteristics

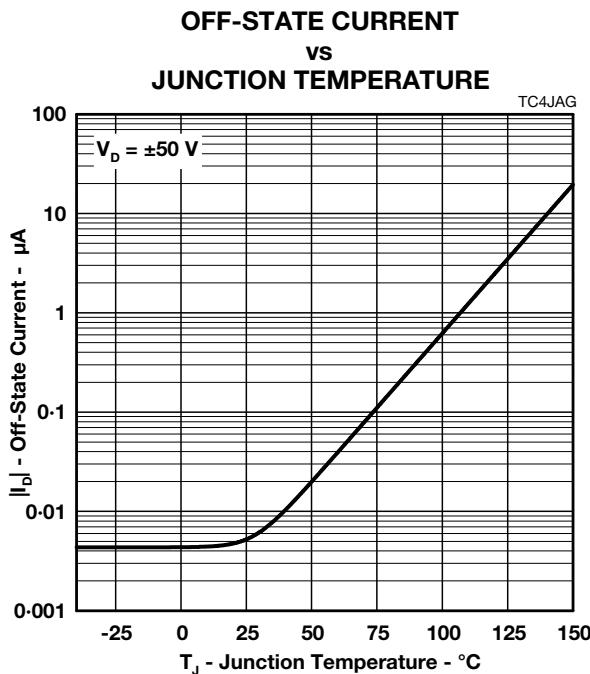


Figure 2.

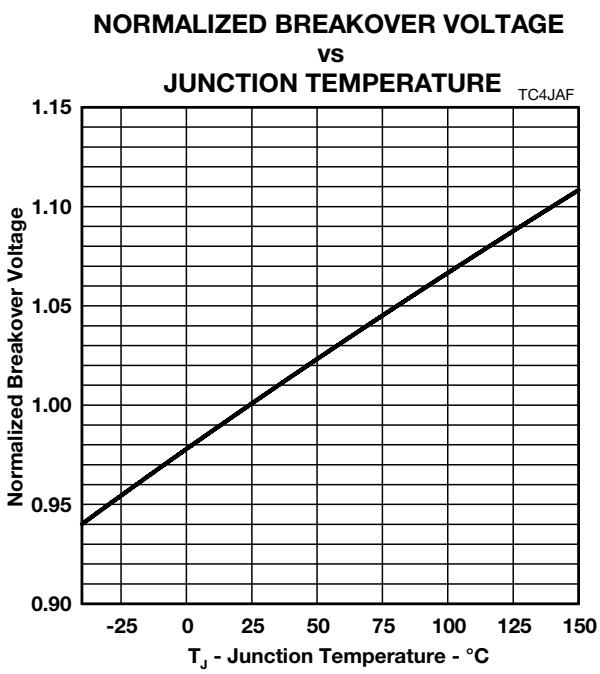


Figure 3.

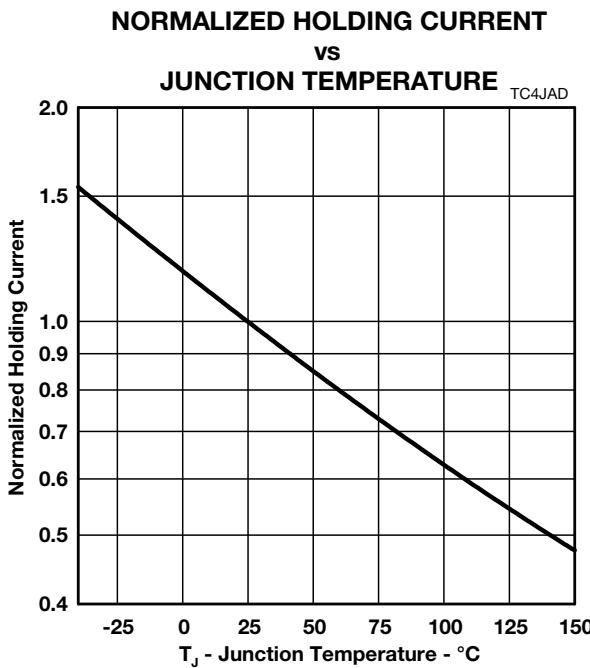


Figure 4.

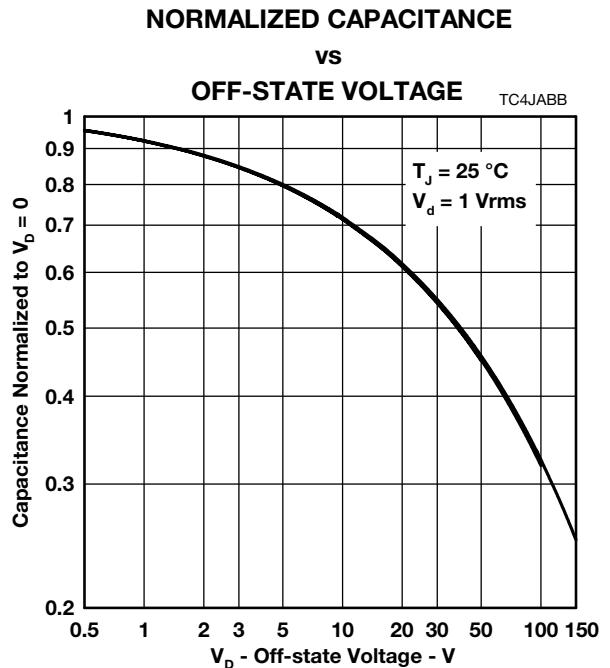


Figure 5.

TISP4xxxJ3BJ Overvoltage Protector Series

BOURNS®

Rating and Thermal Information

NON-REPETITIVE PEAK ON-STATE CURRENT

vs

CURRENT DURATION

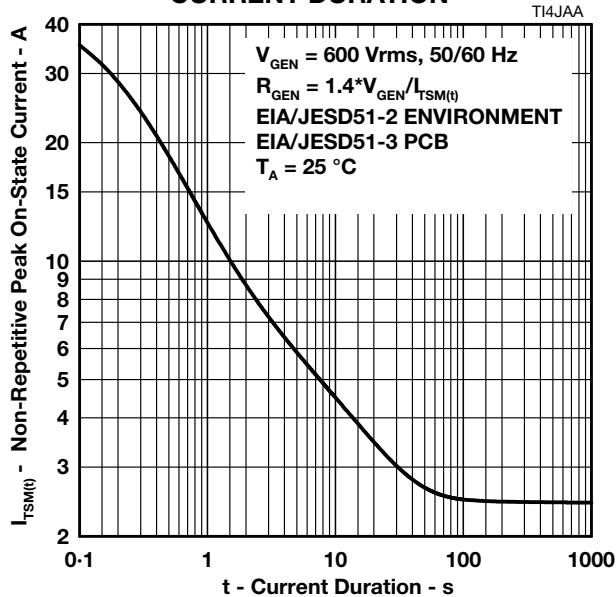


Figure 6.

V_{DRM} DERATING FACTOR

vs

MINIMUM AMBIENT TEMPERATURE

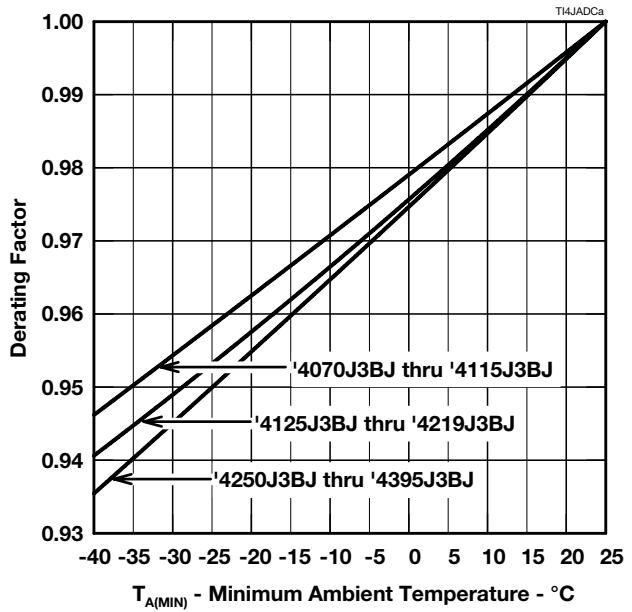


Figure 7.

TISP4xxxJ3BJ Overvoltage Protector Series

BOURNS®

Applications Information

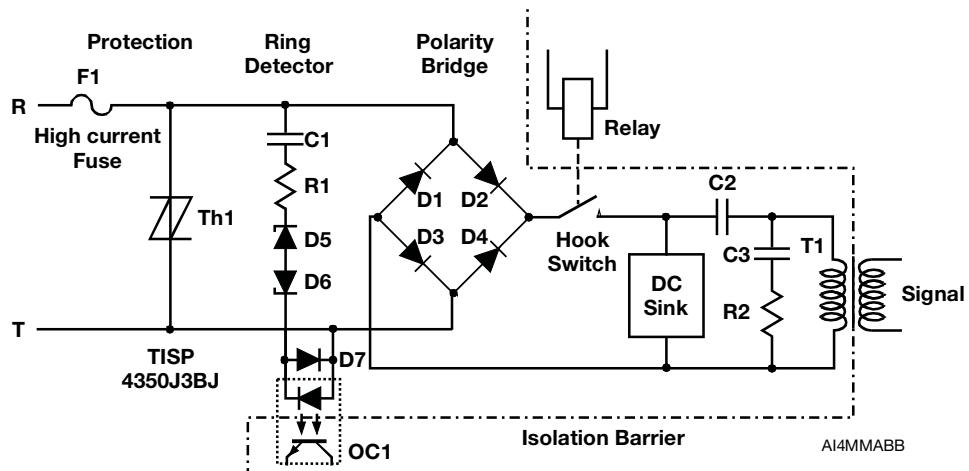


Figure 8. Typical Application Circuit

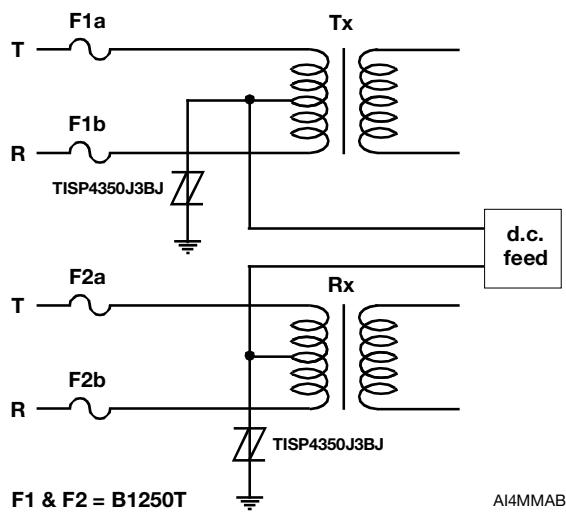


Figure 9. Typical Application Circuit

Bourns Sales Offices

Region	Phone	Fax
The Americas:	+1-951-781-5500	+1-951-781-5700
Europe:	+41-41-7685555	+41-41-7685510
Asia-Pacific:	+886-2-25624117	+886-2-25624116

Technical Assistance

Region	Phone	Fax
The Americas:	+1-951-781-5500	+1-951-781-5700
Europe:	+41-41-7685555	+41-41-7685510
Asia-Pacific:	+886-2-25624117	+886-2-25624116

www.bourns.com

Bourns® products are available through an extensive network of manufacturer's representatives, agents and distributors.
To obtain technical applications assistance, a quotation, or to place an order, contact a Bourns representative in your area.



Reliable Electronic Solutions

"TISP" is a trademark of Bourns, Ltd., a Bourns Company, and is Registered in U.S. Patent and Trademark Office.
"Bourns" is a registered trademark of Bourns, Inc. in the U.S. and other countries.

JULY 2003 – REVISED MAY 2007
Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

Данный компонент на территории Российской Федерации**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибуторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ Р В 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru
moschip.ru_4

moschip.ru_6
moschip.ru_9